

SD1456 (TCC3100)

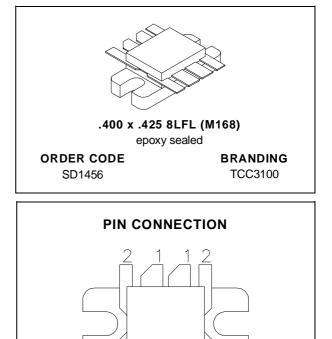
RF & MICROWAVE TRANSISTORS TV/LINEAR APPLICATIONS

1. Collector

2. Emitter

3. Base

- 170 230 MHz
- 28 VOLTS
- CLASS AB PUSH PULL
- DESIGNED FOR HIGH POWER LINEAR OPERATION
- HIGH SATURATED POWER CAPABILITY
- GOLD METALLIZATION
- DIFFUSED EMITTER BALLAST RESISTORS
- COMMON EMITTER CONFIGURATION
- P_{OUT} = 100 W MIN. WITH 11.0 dB GAIN



DESCRIPTION

The SD1456 is a gold metallized epitaxial silicon NPN planar transistor using diffused emitter ballast resistors for high linearity Class AB operation in VHF and Band III television transmitters and transposers.

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^{\circ}C$)

| Symbol | Parameter | Value | Unit |
|------------------|---------------------------|--------------|------|
| V _{CBO} | Collector-Base Voltage | 65 | V |
| V _{CEO} | Collector-Emitter Voltage | 33 | V |
| V _{EBO} | Emitter-Base Voltage | 3.5 | V |
| Ic | Device Current | 16 | А |
| PDISS | Power Dissipation | 150 | W |
| TJ | Junction Temperature | +200 | °C |
| T _{STG} | Storage Temperature | – 65 to +150 | °C |

THERMAL DATA

| R _{TH(j-c)} | Junction-Case Thermal Resistance | 1.2 | °C/W |
|----------------------|----------------------------------|-----|------|
| | | | |
| November 1992 | | | 1/5 |

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ELECTRICAL SPECIFICATIONS $(T_{case} = 25^{\circ}C)$

STATIC

| Symbol | | Test Conditions | | Value | | | Unit |
|------------------------|----------------------|-----------------------|--|-------|------|------|------|
| Symbol Test Conditions | | Test conditions | | Min. | Тур. | Max. | onit |
| ВVсво | $I_C = 50 \text{mA}$ | $I_E = 0mA$ | | 65 | | | V |
| BVCER | $I_C = 50 \text{mA}$ | $R_{BE} = 15\Omega$ | | 60 | _ | _ | V |
| BVCEO | $I_C = 50 \text{mA}$ | $I_B = 0mA$ | | 33 | _ | _ | V |
| BVEBO | $I_E = 5 m A$ | $I_C = 0 m A$ | | 3.5 | _ | | V |
| hfe | $V_{CE} = 5V$ | $I_C = 500 \text{mA}$ | | 20 | _ | 150 | |

DYNAMIC (Class AB)

| Symbol | | Test Conditions | | Value | | | Unit |
|--------|--------------------------|-----------------|----------------------------|-------|------|------|------|
| Symbol | | rest conditions | | | Тур. | Max. | om |
| Pout | f = 225 MHz | $V_{CE} = 28 V$ | $I_{C} = 2 \ x \ 100 \ mA$ | 100 | — | | W |
| GP | P _{OUT} = 100 W | $V_{CE} = 28 V$ | $I_{C} = 2 \ x \ 100 \ mA$ | 11 | — | | dB |
| ηc | $P_{OUT} = 100 W$ | $V_{CE} = 28 V$ | $I_{C} = 2 \ x \ 100 \ mA$ | 70 | _ | | % |
| Сов | f = 1 MHz | $V_{CB} = 28 V$ | | | 60 | | pF |

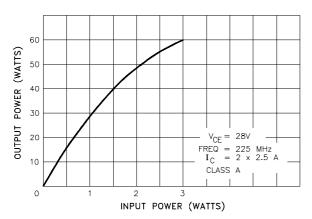
DYNAMIC (Class A)

| Symbol | | Test Conditions | | Value | | Unit | |
|--------------------|-------------------------|-----------------|----------------------------------|-------|------|------|----|
| Symbol | | Test conditions | | Min. | Тур. | Max. | om |
| Pout* | f = 225 MHz | $V_{CE} = 28 V$ | $I_{C} = 2 \times 2.5 A$ | 28 | 32 | | W |
| G _P * | P _{IN} = 1.1 W | $V_{CE} = 28 V$ | $I_{C} = 2 \times 2.5 \text{ A}$ | 14 | 15 | | dB |
| IMD ₃ * | $P_{IN} = 1.1 W$ | $V_{CE} = 28 V$ | $P_{REF} = 28 W$ | — | -51 | | dB |

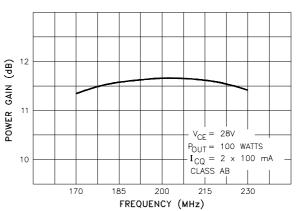
Note: * Class A Performance Characteristics Indicate Capability but are not Tested. IMD3 - 3 Tone Meaurement; -8, -7, -16dB relative to P_{REF}

TYPICAL PERFORMANCE

POWER OUTPUT vs POWER INPUT

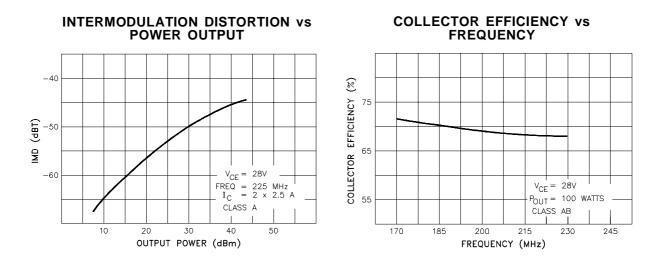


BROADBAND POWER GAIN vs FREQUENCY

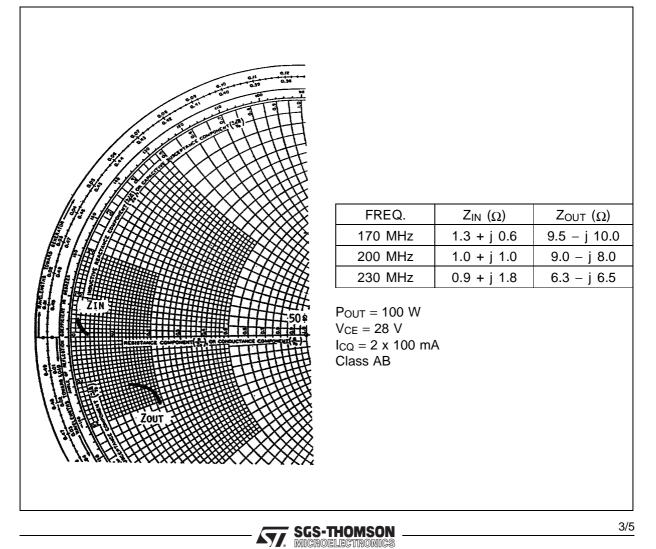




TYPICAL PERFORMANCE (cont'd)

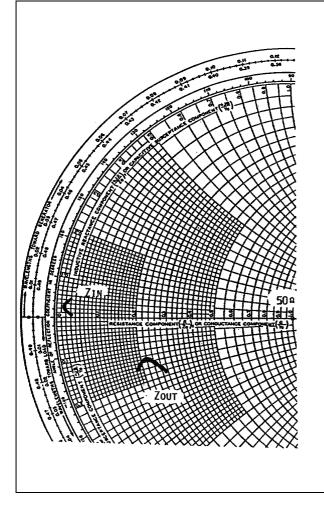


IMPEDANCE DATA

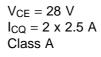


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IMPEDANCE DATA

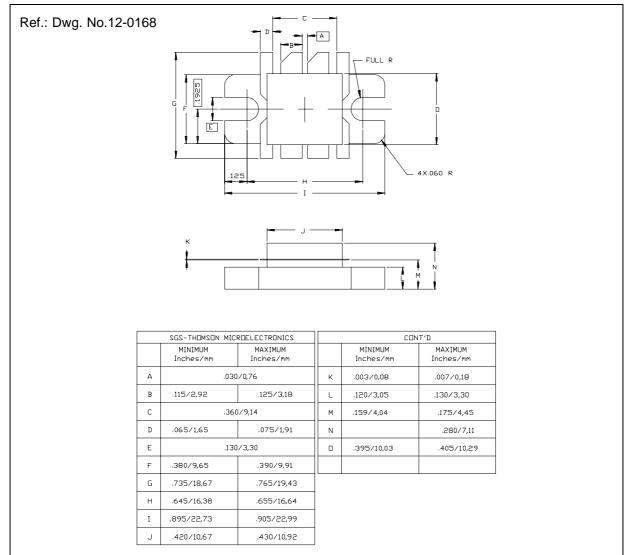


| FREQ. | Z _{IN} (Ω) | Z _{OUT} (Ω) |
|---------|---------------------|----------------------|
| 170 MHz | 1.05 + j 0.65 | 13.5 – j 9.0 |
| 200 MHz | 0.9 + j 1.1 | 11.0 – j 6.5 |
| 230 MHz | 1.25 + j 1.8 | 9.5 – j 7.7 |





PACKAGE MECHANICAL DATA



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